U.S. Ser. No. 10/663,531 Our File: MIT 9983

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT:

Tuller et al.

GROUP:

2815

SERIAL NO:

10/663,531

EXAMINER: M. Landau

FILED:

September 16, 2003

FOR:

METHOD FOR P-TYPE DOPING OF WIDE BAND GAP

OXIDE SEMICONDUCTORS

Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

AMENDMENT

In response to the Office Action mailed January 10, 2008, please amend the above-identified application as follows: